

2019-03-01

Revision 1.11

GAIN CHIPS AR coated Fabry-Perot Laser

Application
Spectroscopy
Covering popular wavelengths
between 810 and 860 nm



Absolute Maximum Ratings

Parameter	Symbol	Unit	min	typ	max
Storage Temperature	Ts	°C	-40		85
Operational Temperature at Case	Tc	°C	-20		50
Forward Current	I _F	mA			200
Reverse Voltage	V _R	V			0
Output Power (extracavity)	P _{opt}	mW			100

Recommended Operational Conditions

Parameter	Symbol	Unit	min	typ	max
Operational Temperature at Case	T _C	°C	15		40
Forward Current	Ι _F	mA			180
	I _C	mA	15		

Characteristics at T_{LD} = 25 °C at BOL, with external cavity under recommended working condition

Parameter	Symbol	Unit	min	typ	max
Center Wavelength	λ _c	nm		840	
Tuning Range	$\Delta\lambda_{tun}$	nm	810		860
Output Power	P _{opt}	mW		50	
Polarization				TE	
Output Power	P _{opt}	W		50	
Spatial Mode (transversal)				TEM00	



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Measurement Conditions / Comments

Stess in excess of the Absolute Maximum Ratings can cause permanent damage to the device.

Measurement Conditions / Comments

Measurement Conditions / Comments The actual achieved wavelength and power are strongly influenced by the external cavity. eyP gives no guarantee on these parameters.

E field parallel to Pin 2 - Pin 3 - plane

Fundamental Mode





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TOPTICA

Amplified Spontaneous Emiss without external cavity	ion (ASE)			
Parameter	Symbol	Unit mi	n typ	max
Divergence parallel (FWHM)	$\Theta_{ }$		10	
Divergence perpendicular (FWHM)	Θ_{\perp}		23	
Monitor Detector Responsivity	I _{mon} / P _{ASE} μ/	4/mW 1		40

Chip Parameter

Parameter	Symbol	Unit	min	typ	max
Cavity Length	L	μm		1500	
Reflectivity at Front Facet	R _{ff}			3·10 ⁻⁴	1·10 ⁻³

Measurement Conditions / Comments
parallel to Pin 2 - Pin 3 plane (see p. 3)
perpendicular to Pin 2 - Pin 3 plane (see p. 3)
$U_{R MD} = 5 V$

Measurement Conditions / Comments





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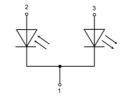
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Symbol	Unit	min	typ	max
h	mm	3.50	3.65	3.70
R	mm			0.12
L _{PIN}	mm		14	
	h R	h mm R mm	h mm 3.50 R mm	h mm 3.50 3.65 R mm

Measurement Conditions / Comments
reference plane: top side of TO header
reference: center of outer diameter of header

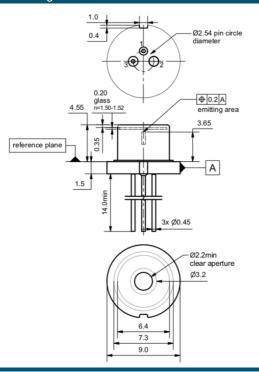
Package Pinout

- 1 Laser Diode Cathode, Monitor Diode Cathode, Case
- 2 Photo Diode Anode
- 3 Laser Diode Anode





Package Drawings





AIZ-16-0421-1517

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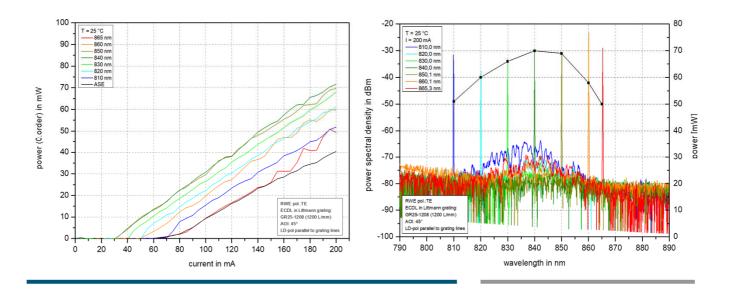


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Typical Measurement Results



Unpacking, Installation and Laser Safety

Unpacking the laser diodes should only be done at electrostatic safe workstations (EPA). Though protection against electro static discharge (ESD) is implemented in the laser package, charges may occur at surfaces. Please store this product in its original package at a dry, clean place until final use. During device installation, ESD protection has to be maintained.

The TPA diode type is known to be sensitive against thermal stress. It should not be operated without appropriate injection from a seed laser. Operating at moderate temperatures on proper heat sinks will contribute to a long lifetime of the diode. The chip should be protected against moisture. A water vapor content below 5000 ppm is recommended for applications with high reliability requirements.

The laser emission from this diode is close to the invisible infrared region of the electromagnetic spectrum. Avoid direct and/or indirect exposure to the free running beam. Collimating the free running beam with optics as common in optical instruments will increase threat to the human eye.

Each laser diode will come with an individual test protocol verifying the parameters given in this document.











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